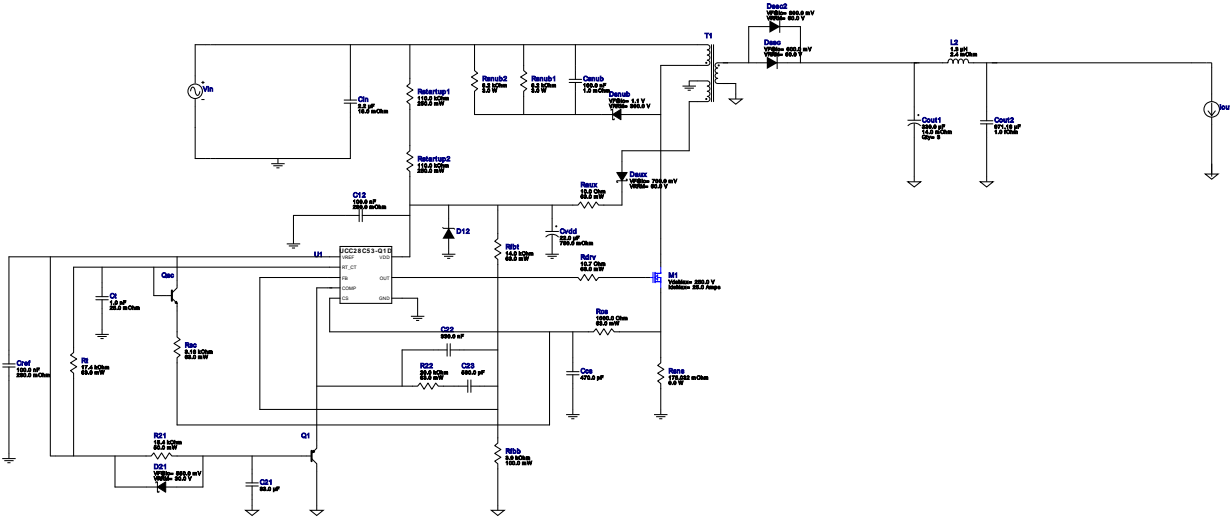


# WEBENCH® Design Report

Design : 14 UCC28C53QDRQ1  
UCC28C53QDRQ1 50V-85V to 12.00V @ 5A

VinMin = 50.0V  
VinMax = 85.0V  
Vout = 12.0V  
Iout = 5.0A

Device = UCC28C53QDRQ1  
Topology = Flyback  
Created = 2023-08-04 07:34:18.956  
BOM Cost = NA  
BOM Count = 40  
Total Pd = 5.5W



1. This regulator device is qualified for Automotive applications. All passives and other components selected in this design may not be qualified for Automotive applications. The user is required to verify that all components in the design meet the qualification and safety requirements for their specific application. View WEBENCH(R) Disclaimer.

## Design Alerts

















### Component Selection Information

The UCC28C53-Q1 is qualified for Automotive applications. All passives and other components selected in this design may not be qualified for Automotive applications. The user is required to verify that all components in the design meet the qualification and safety requirements for their specific application. Click on the transformer symbol in the schematic and select "Explore Transformer Core/Bobbin Selection" to design using specific transformer cores and bobbin.

## Electrical BOM

| Name | Manufacturer              | Part Number                           | Properties   | Qty | Price  | Footprint                 |
|------|---------------------------|---------------------------------------|--|-----|--------|---------------------------|
| C12  | AVX                       | 0805C104KAT2A<br>Series= X7R          | Cap= 100.0 nF<br>ESR= 280.0 mOhm<br>VDC= 25.0 V<br>IRMS= 0.0 A | 1   | \$0.01 | 0805 7 mm <sup>2</sup>    |
| C21  | MuRata                    | KCM55WR7YA336MH01K<br>Series= X7R     | Cap= 33.0 uF<br>VDC= 35.0 V<br>IRMS= 0.0 A                     | 1   | \$2.81 | KCM55W 59 mm <sup>2</sup> |
| C22  | Panasonic                 | ECPU1C334MA5<br>Series= ECPU(A)       | Cap= 330.0 nF<br>VDC= 16.0 V<br>IRMS= 0.0 A                    | 1   | \$0.23 | 1206 11 mm <sup>2</sup>   |
| C23  | MuRata                    | GRM1555C1H561JA01J<br>Series= C0G/NP0 | Cap= 560.0 pF<br>VDC= 50.0 V<br>IRMS= 0.0 A                    | 1   | \$0.01 | 0402 3 mm <sup>2</sup>    |
| Ccs  | Samsung Electro-Mechanics | CL21C471JBANNNC<br>Series= C0G/NP0    | Cap= 470.0 pF<br>VDC= 50.0 V<br>IRMS= 0.0 A                    | 1   | \$0.01 | 0805 7 mm <sup>2</sup>    |

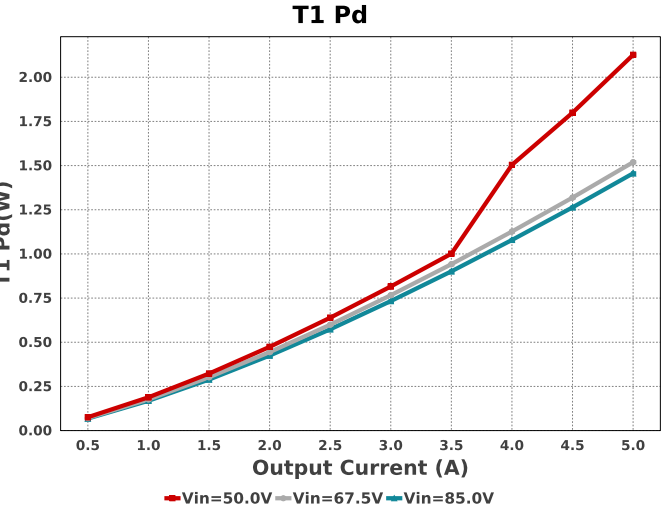
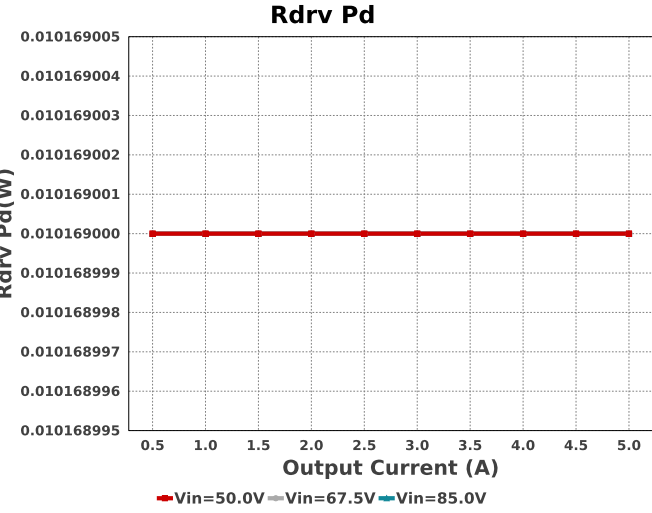
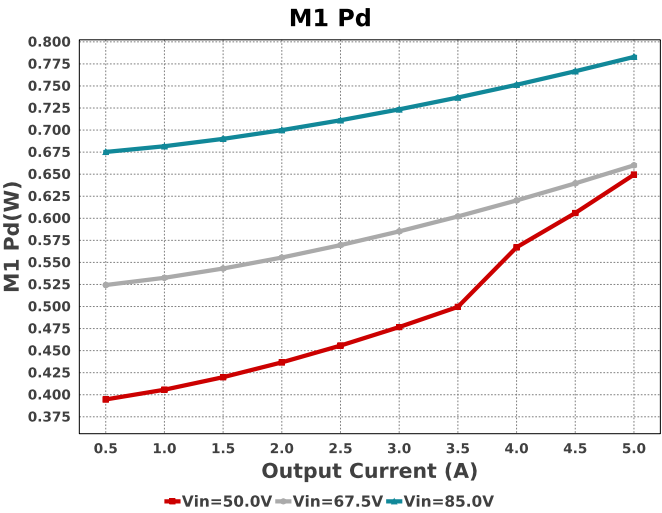
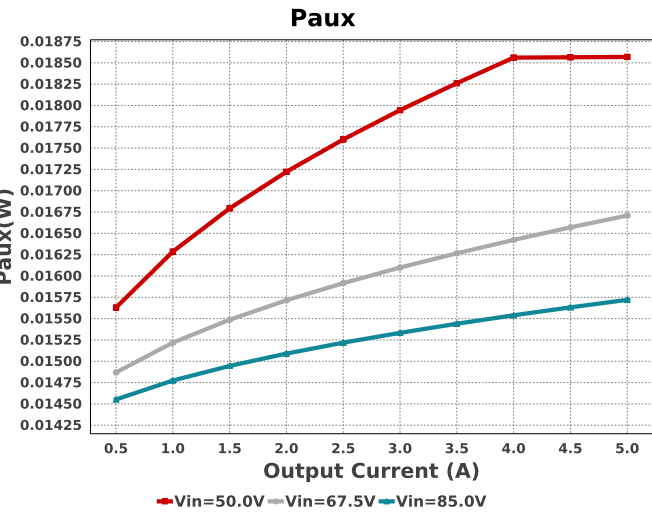
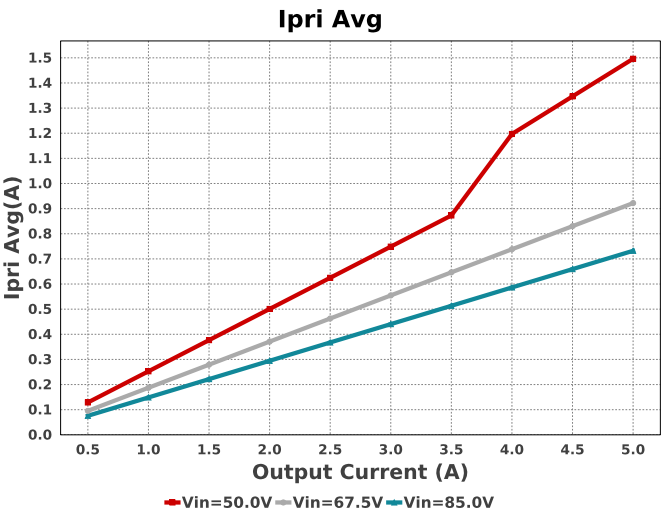
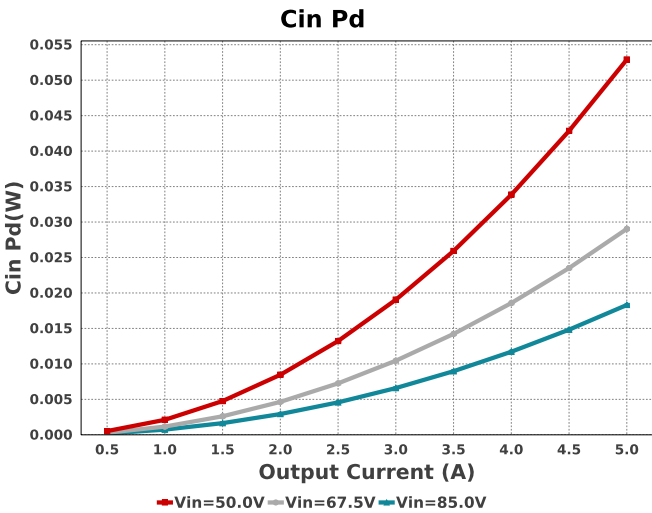
| Name  | Manufacturer            | Part Number                         | Properties   | Qty | Price  | Footprint   |
|-------|-------------------------|-------------------------------------|--|-----|--------|---|
| Cin   | TDK                     | B32674D3225K<br>Series= B32674      | Cap= 2.2 uF<br>ESR= 18.0 mOhm<br>VDC= 300.0 V<br>IRMS= 5.0 A     | 1   | \$0.92 | <br>B32674_3150x1900x1100<br>436 mm <sup>2</sup> |
| Cout1 | Panasonic               | 25SVPF330M<br>Series= SVPF          | Cap= 330.0 uF<br>ESR= 14.0 mOhm<br>VDC= 25.0 V<br>IRMS= 5.0 A    | 3   | \$1.33 | <br>CAPSMT_62_F12 151 mm <sup>2</sup>            |
| Cout2 | CUSTOM                  | CUSTOM<br>Series= ?                 | Cap= 971.16 uF<br>ESR= 1.0 fOhm<br>VDC= 30.0 V<br>IRMS= 9.3402 A | 1   | NA     | CUSTOM 0 mm <sup>2</sup>  |
| Cref  | AVX                     | 08053C104KAT2A<br>Series= X7R       | Cap= 100.0 nF<br>ESR= 280.0 mOhm<br>VDC= 25.0 V<br>IRMS= 0.0 A   | 1   | \$0.01 | <br>0805 7 mm <sup>2</sup>                       |
| Csnub | TDK                     | C2012X7T2E104K125AA<br>Series= X7T  | Cap= 100.0 nF<br>ESR= 1.0 mOhm<br>VDC= 250.0 V<br>IRMS= 0.0 A    | 1   | \$0.09 | <br>0805 7 mm <sup>2</sup>                       |
| Ct    | Kemet                   | C0805C102J5GACTU<br>Series= C0G/NP0 | Cap= 1.0 nF<br>ESR= 25.0 mOhm<br>VDC= 50.0 V<br>IRMS= 1.71 A     | 1   | \$0.02 | <br>0805 7 mm <sup>2</sup>                       |
| Cvdd  | Nichicon                | UUD1V220MCL1GS<br>Series= uD        | Cap= 22.0 uF<br>ESR= 760.0 mOhm<br>VDC= 35.0 V<br>IRMS= 150.0 mA | 1   | \$0.14 | <br>SM_RADIAL_5MM 58 mm <sup>2</sup>           |
| D12   | Diodes Inc.             | MMSZ5248B-7-F                       | Zener  | 1   | \$0.04 | <br>SOD-123 13 mm <sup>2</sup>                 |
| D21   | Panasonic               | DB2S31600L                          | VF@Io= 550.0 mV<br>VRRM= 30.0 V                                  | 1   | \$0.03 | <br>SOD-523 5 mm <sup>2</sup>                  |
| Daux  | Fairchild Semiconductor | SS26FL                              | VF@Io= 700.0 mV<br>VRRM= 60.0 V                                  | 1   | \$0.11 | <br>SOD-123F 12 mm <sup>2</sup>                |
| Dsec  | Diodes Inc.             | STPS30M60                           | VF@Io= 600.0 mV<br>VRRM= 60.0 V                                  | 1   | \$0.79 | <br>TO-220AB 79 mm <sup>2</sup>                |
| Dsec2 | Diodes Inc.             | STPS30M60                           | VF@Io= 600.0 mV<br>VRRM= 60.0 V                                  | 1   | \$0.79 | <br>TO-220AB 79 mm <sup>2</sup>                |
| Dsnub | SMC Diode Solutions     | ST1300ATR                           | VF@Io= 1.1 V<br>VRRM= 300.0 V                                    | 1   | \$0.12 | <br>SMA 37 mm <sup>2</sup>                     |
| L2    | Coilcraft               | MLC1250-132MLB                      | L= 1.3 uH<br>2.4 mOhm  | 1   | \$0.79 | <br>MLC1250 165 mm <sup>2</sup>                |
| M1    | Infineon Technologies   | BSC600N25NS3GATMA1                  | VdsMax= 250.0 V<br>IdsMax= 25.0 Amps                             | 1   | \$2.26 | <br>PG-TDSON-8 55 mm <sup>2</sup>              |

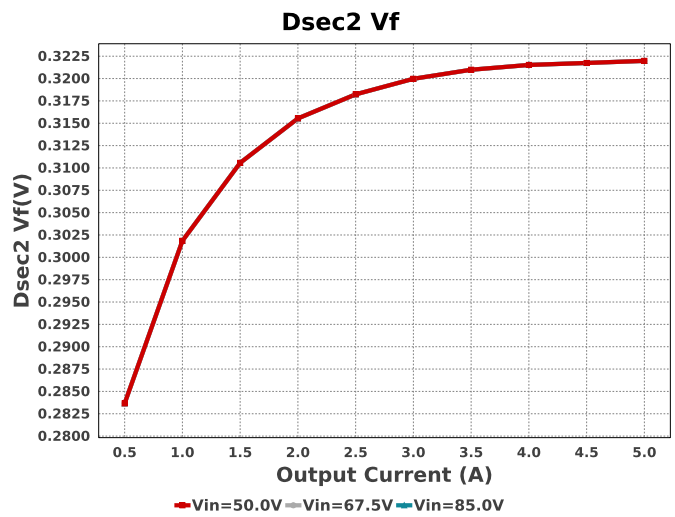
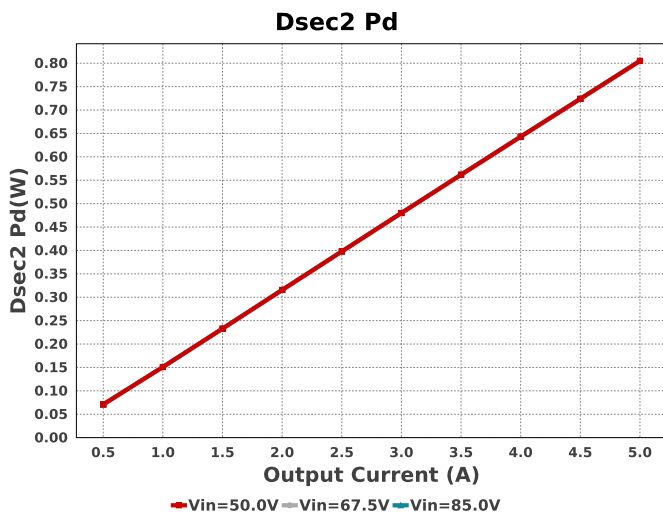
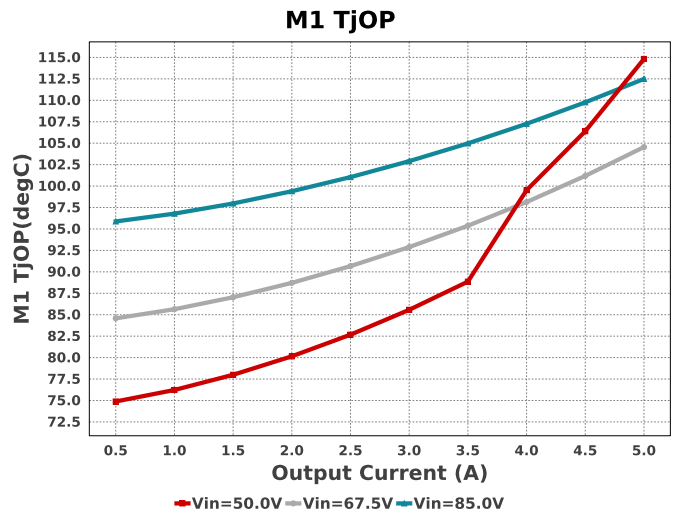
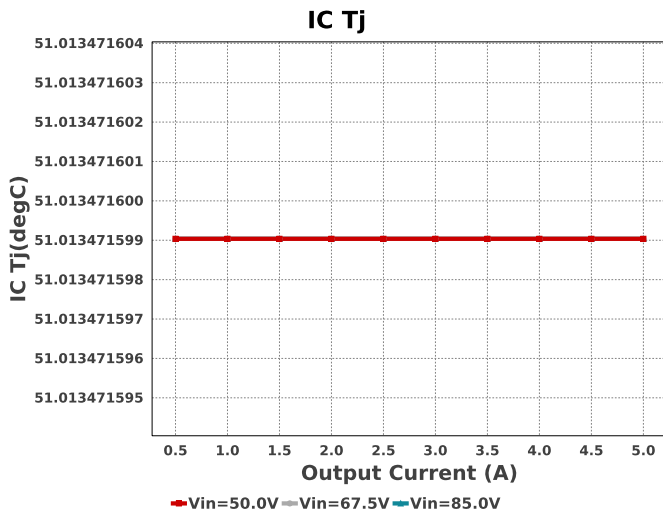
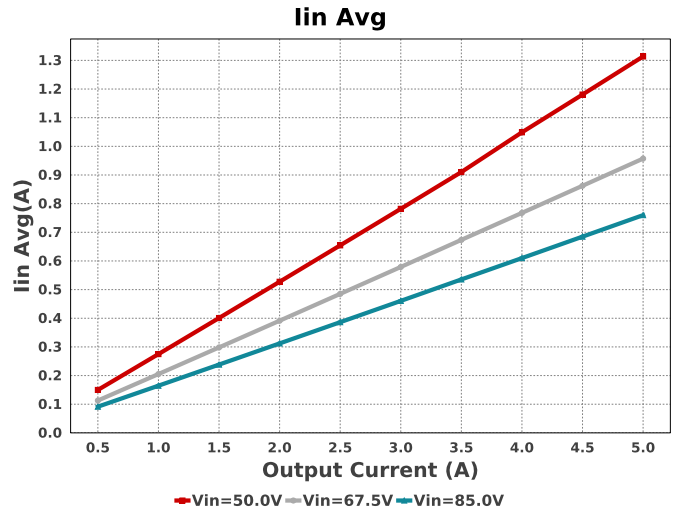
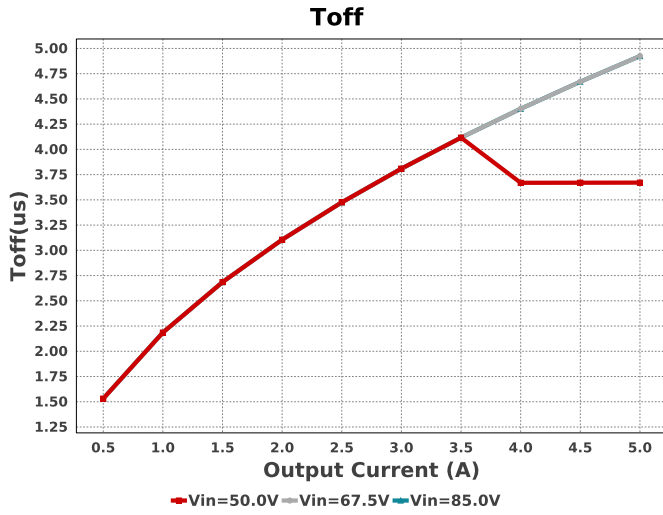
| Name      | Manufacturer                 | Part Number  | Properties   | Qty | Price  | Footprint   |
|-----------|------------------------------|--|--|-----|--------|---|
| Q1        | Diodes Inc.                  | MMBT3906-7-F   | Bipolar Transistor   | 1   | \$0.02 | <br>SOT-23 14 mm <sup>2</sup>        |
| Qsc       | STMicroelectronics           | 2N2222A  | Bipolar Transistor   | 1   | \$1.19 | <br>TO-18 57 mm <sup>2</sup>         |
| R21       | Yageo                        | RC0201FR-0715K4L<br>Series= ?                        | Res= 15.4 kOhm<br>Power= 50.0 mW<br>Tolerance= 1.0%  | 1   | \$0.01 | <br>0201 2 mm <sup>2</sup>           |
| R22       | Vishay-Dale                  | CRCW040220K0FKED<br>Series= CRCW..e3                 | Res= 20.0 kOhm<br>Power= 63.0 mW<br>Tolerance= 1.0%  | 1   | \$0.01 | <br>0402 3 mm <sup>2</sup>           |
| Raux      | Vishay-Dale                  | CRCW040210R0FKED<br>Series= CRCW..e3                 | Res= 10.0 Ohm<br>Power= 63.0 mW<br>Tolerance= 1.0%   | 1   | \$0.01 | <br>0402 3 mm <sup>2</sup>           |
| Rcs       | Vishay-Dale                  | CRCW04021K00FKED<br>Series= CRCW..e3                 | Res= 1000.0 Ohm<br>Power= 63.0 mW<br>Tolerance= 1.0%   | 1   | \$0.01 | <br>0402 3 mm <sup>2</sup>           |
| Rdrv      | Vishay-Dale                  | CRCW040210R7FKED<br>Series= CRCW..e3                 | Res= 10.7 Ohm<br>Power= 63.0 mW<br>Tolerance= 1.0%   | 1   | \$0.01 | <br>0402 3 mm <sup>2</sup>           |
| Rfbb      | Yageo                        | RC0603FR-073K9L<br>Series= ?                         | Res= 3.9 kOhm<br>Power= 100.0 mW<br>Tolerance= 1.0%  | 1   | \$0.01 | <br>0603 5 mm <sup>2</sup>           |
| Rfbt      | Vishay-Dale                  | CRCW040214K0FKED<br>Series= CRCW..e3                 | Res= 14.0 kOhm<br>Power= 63.0 mW<br>Tolerance= 1.0%  | 1   | \$0.01 | <br>0402 3 mm <sup>2</sup>           |
| Rsc       | Vishay-Dale                  | CRCW04023K16FKED<br>Series= CRCW..e3                 | Res= 3.16 kOhm<br>Power= 63.0 mW<br>Tolerance= 1.0%  | 1   | \$0.01 | <br>0402 3 mm <sup>2</sup>         |
| Rsns      | CUSTOM                       | CUSTOM<br>Series= ?                                  | Res= 175.032 mOhm<br>Power= 0.0 W<br>Tolerance= 0.0%   | 1   | NA     | CUSTOM 0 mm <sup>2</sup>  |
| Rsub1     | Vishay-Bccomponents          | PR03000208201JAC00<br>Series= ?                      | Res= 8.2 kOhm<br>Power= 3.0 W<br>Tolerance= 5.0%   | 1   | \$0.18 | <br>PR03 197 mm <sup>2</sup>       |
| Rsub2     | Vishay-Bccomponents          | PR03000208201JAC00<br>Series= ?                      | Res= 8.2 kOhm<br>Power= 3.0 W<br>Tolerance= 5.0%   | 1   | \$0.18 | <br>PR03 197 mm <sup>2</sup>       |
| Rstartup1 | Vishay-Dale                  | CRCW1206110KFKEA<br>Series= CRCW..e3                 | Res= 110.0 kOhm<br>Power= 250.0 mW<br>Tolerance= 1.0%  | 1   | \$0.01 | <br>1206 11 mm <sup>2</sup>        |
| Rstartup2 | Vishay-Dale                  | CRCW1206110KFKEA<br>Series= CRCW..e3                 | Res= 110.0 kOhm<br>Power= 250.0 mW<br>Tolerance= 1.0%  | 1   | \$0.01 | <br>1206 11 mm <sup>2</sup>        |
| Rt        | Vishay-Dale                  | CRCW040217K4FKED<br>Series= CRCW..e3                 | Res= 17.4 kOhm<br>Power= 63.0 mW<br>Tolerance= 1.0%  | 1   | \$0.01 | <br>0402 3 mm <sup>2</sup>         |
| T1        | Core=TDK ,<br>CoilFormer=TDK | Core=B66421G0000X197 ,<br>CoilFormer=B66422W1010D001 | Lp= 87.0 µH<br>Turns Ratio(Nas)= 6:5<br>Turns Ratio(Nps)= 27:5<br>Npri= 27.0<br>Naux= 6.0<br>Nsec= 5.0 | 1   | \$0.49 | <br>TDK_B66305 756 mm <sup>2</sup> |

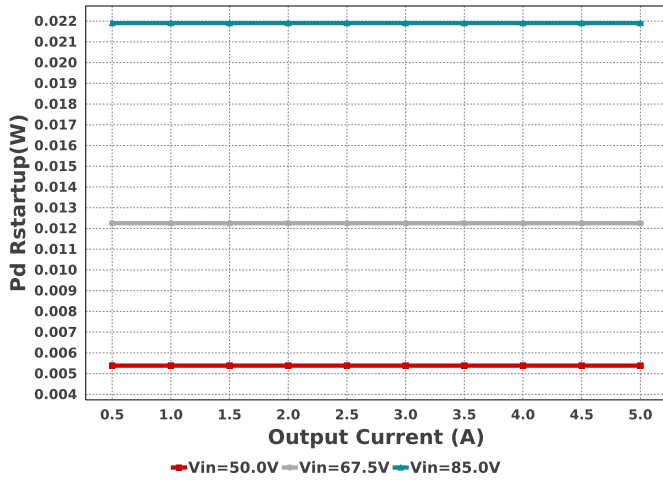
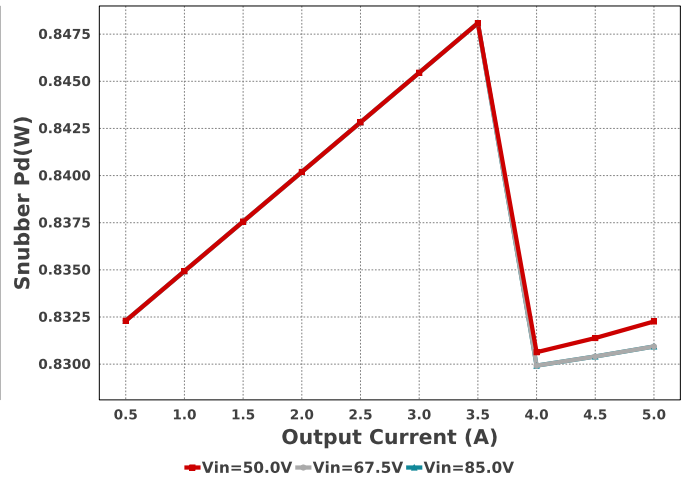
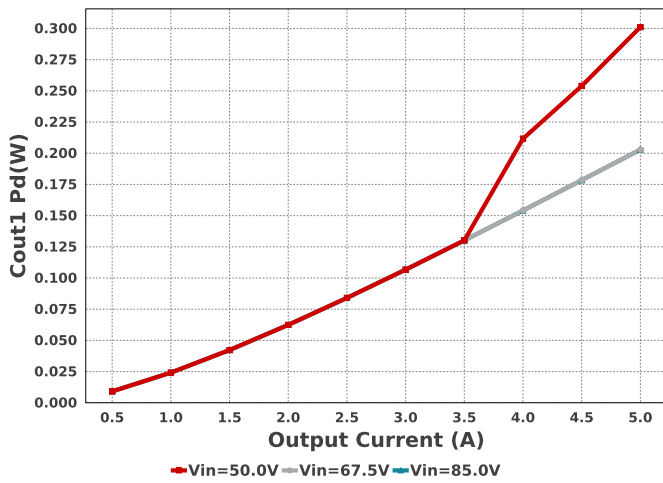
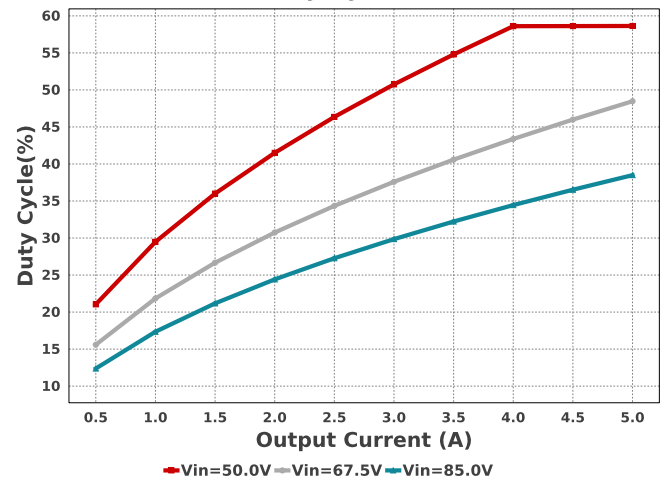
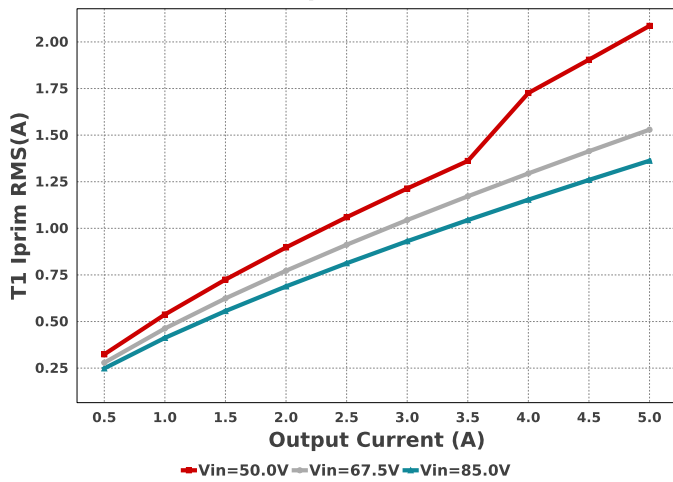
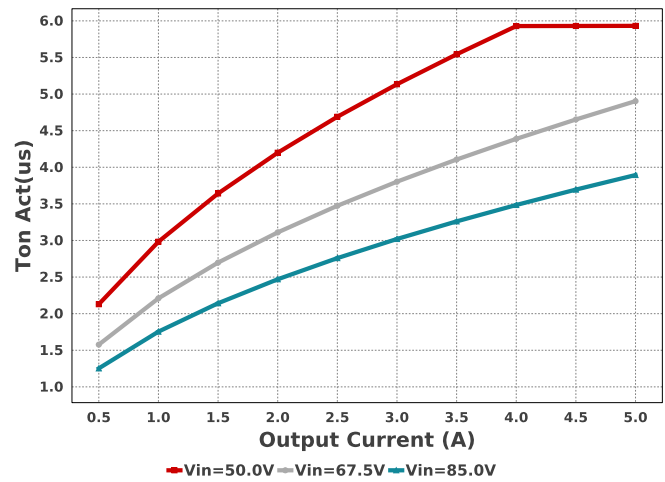
| Name | Manufacturer      | Part Number   | Properties | Qty | Price  | Footprint |
|------|-------------------|---------------|------------|-----|--------|-----------|
| U1   | Texas Instruments | UCC28C53QDRQ1 | Switcher   | 1   | \$0.67 |           |

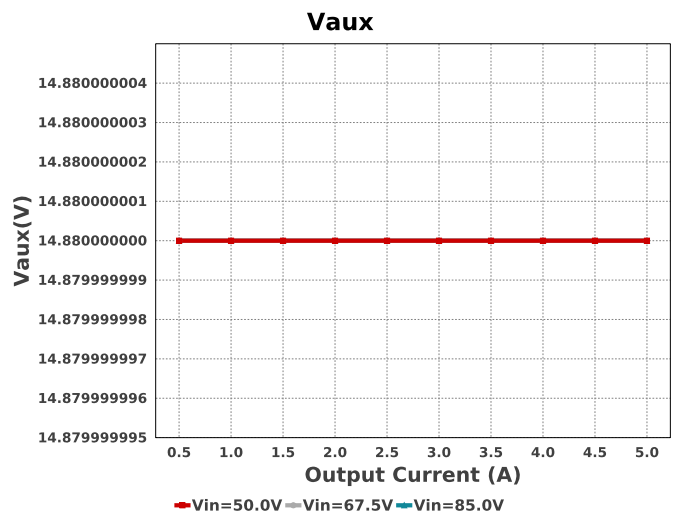
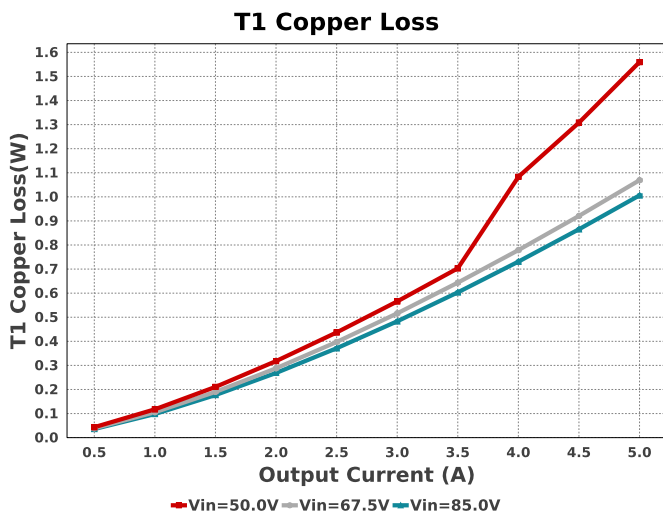
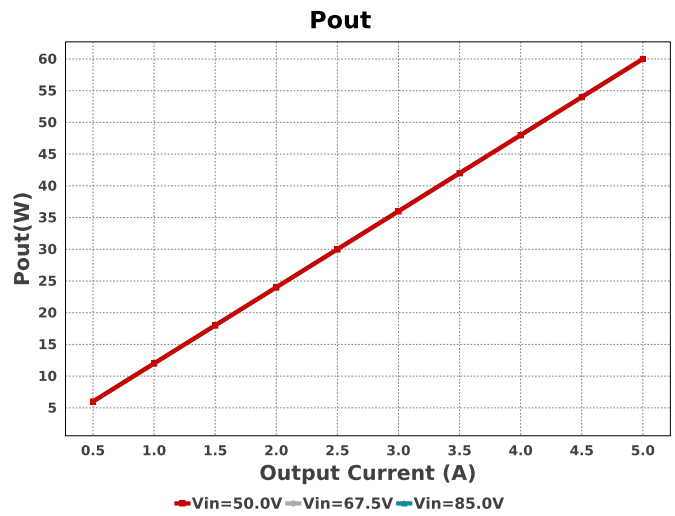
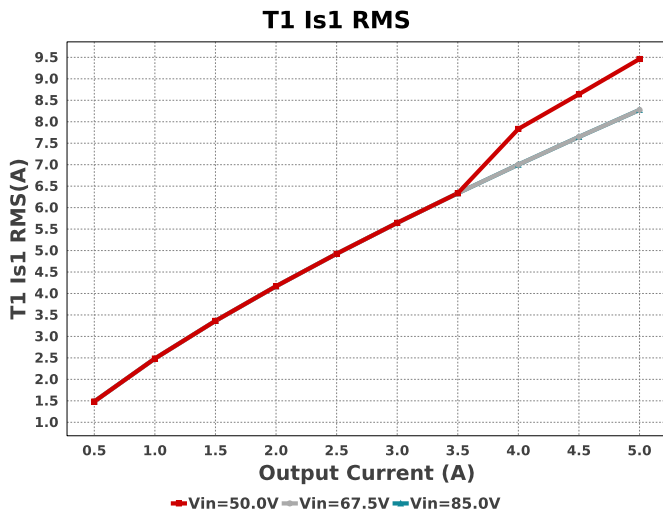
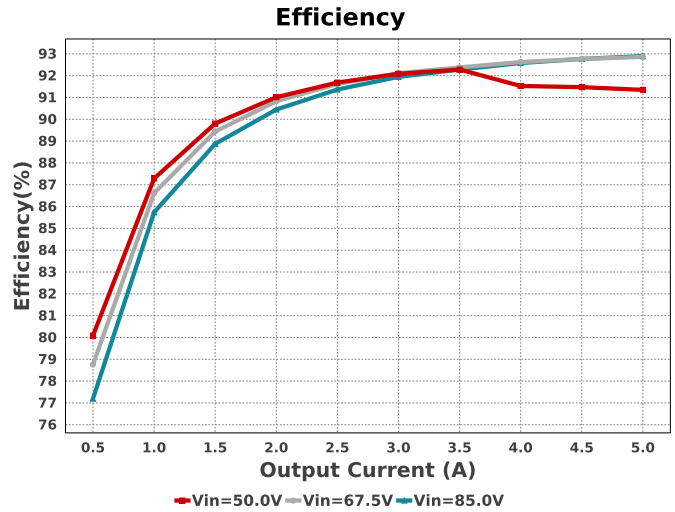
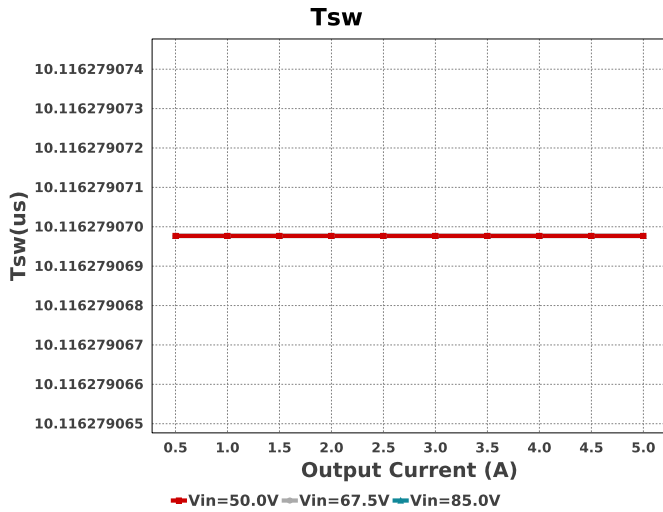


D0008A 57 mm<sup>2</sup>



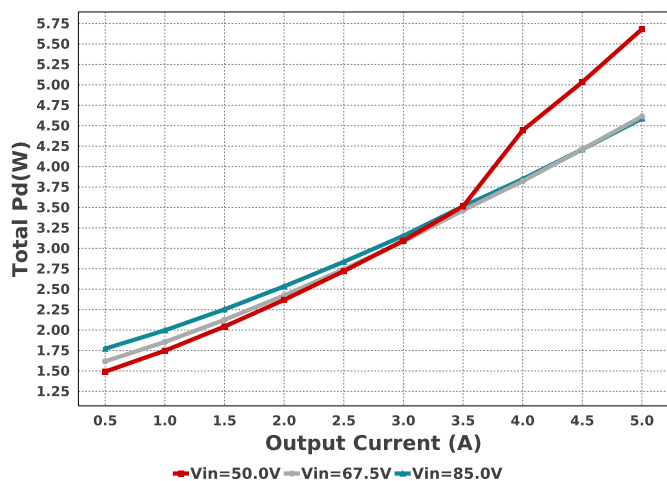


**Pd Rstartup****Snubber Pd****Cout1 Pd****Duty Cycle****T1 Iprim RMS****Ton Act**

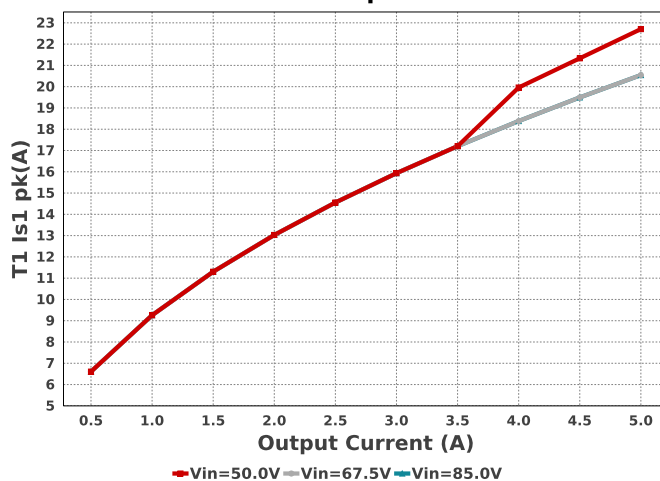




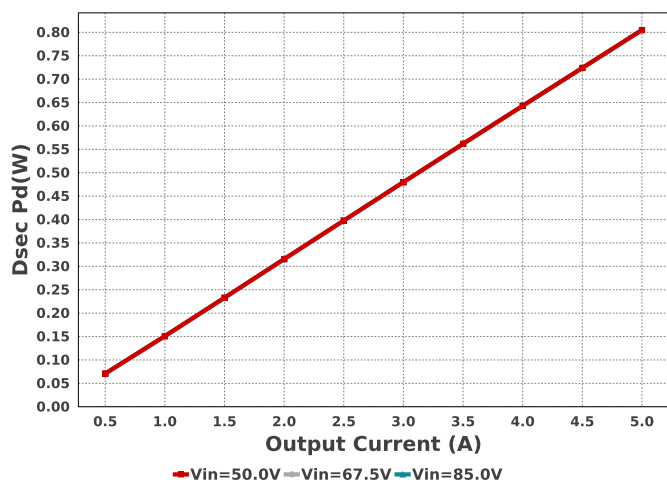
Total Pd



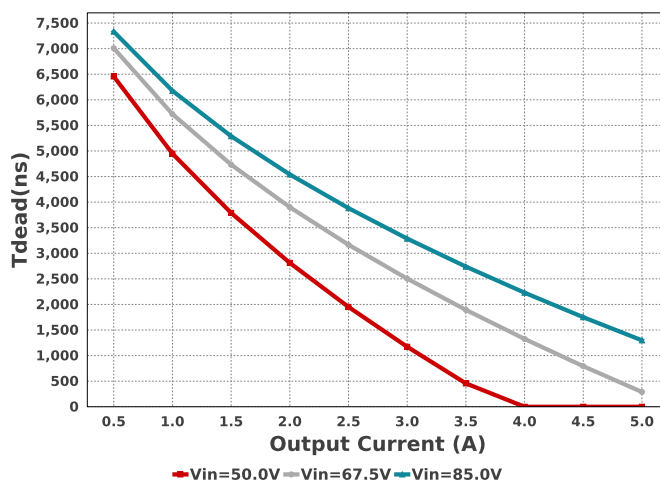
T1 Is1 pk



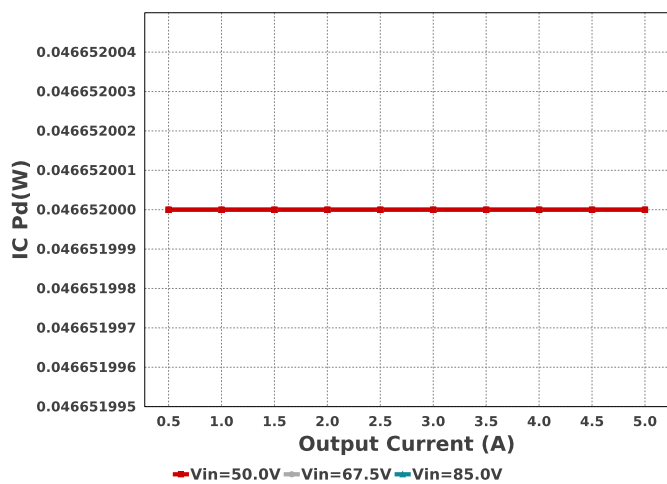
Dsec Pd



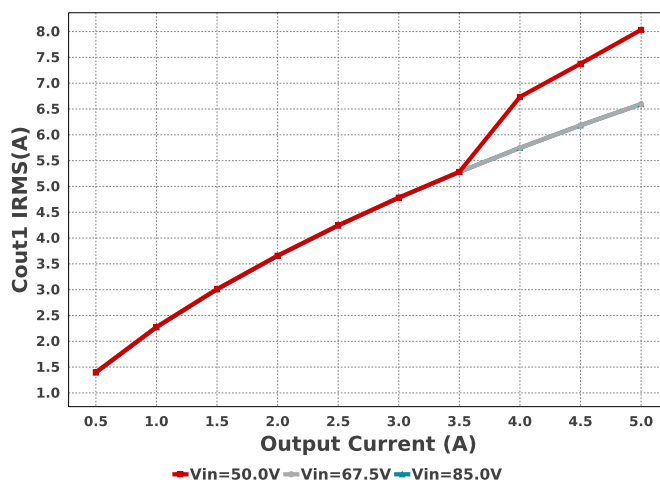
Tdead



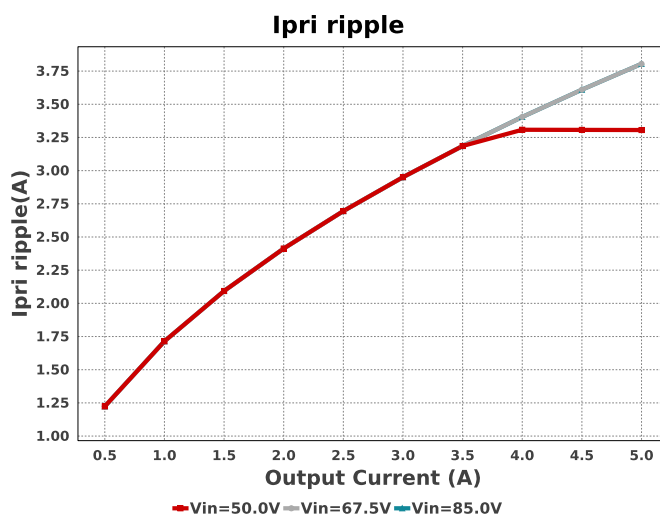
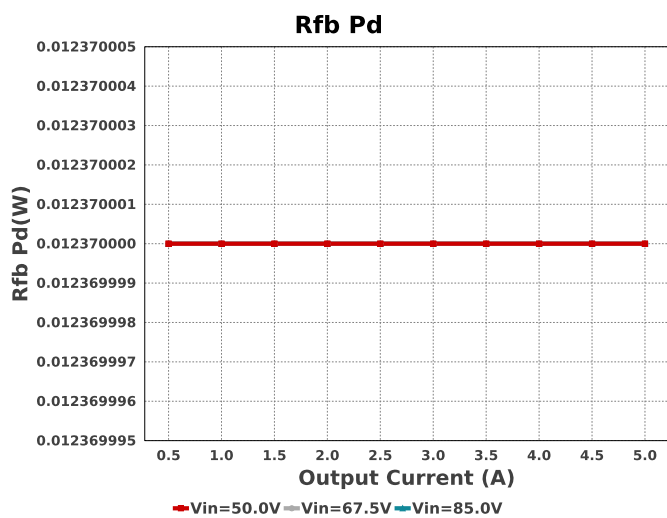
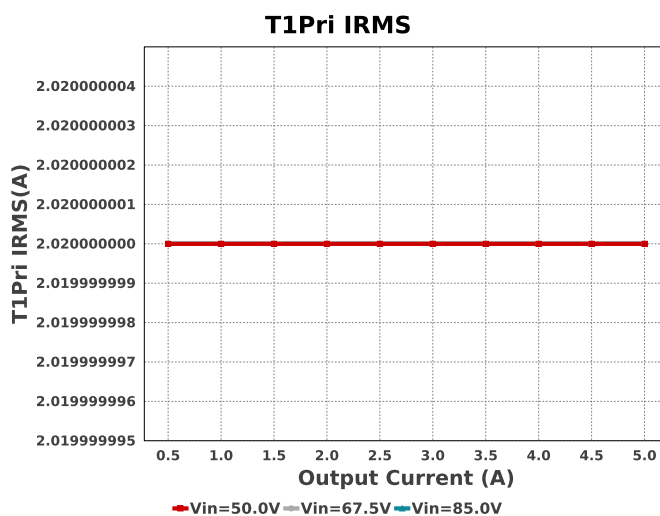
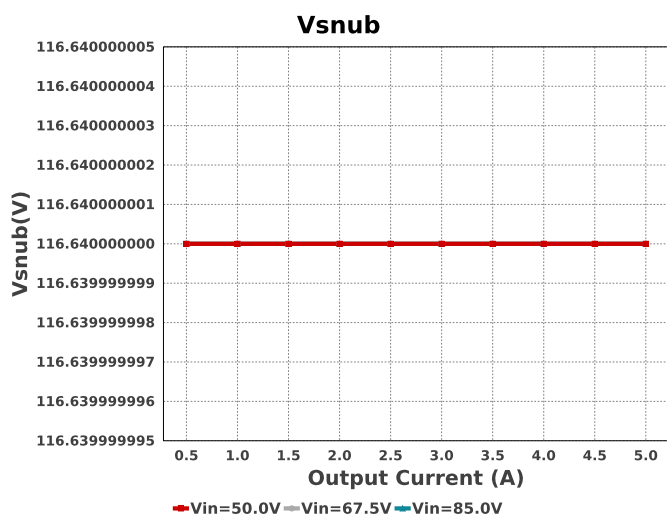
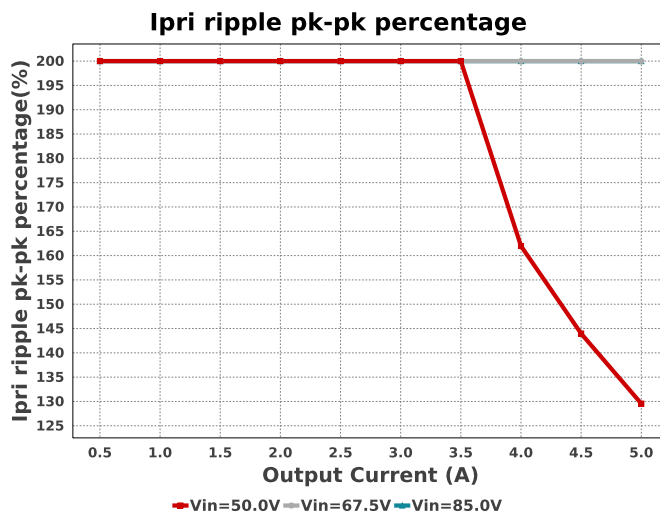
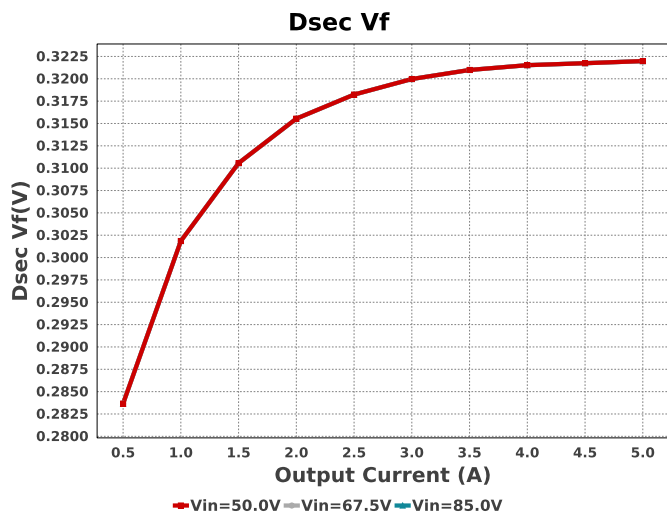
IC Pd



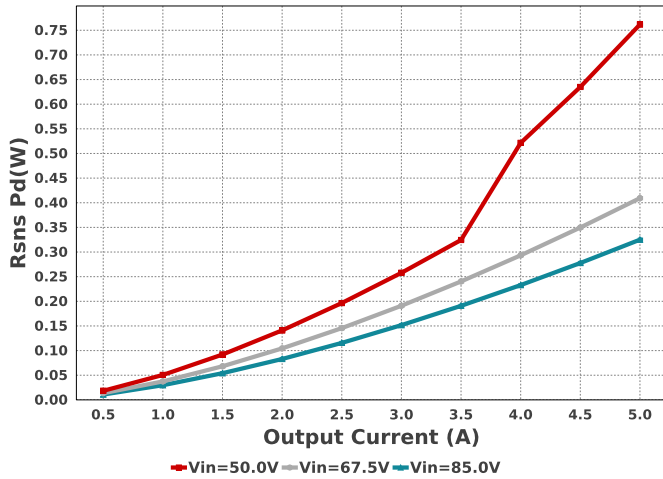
Cout1 IRMS



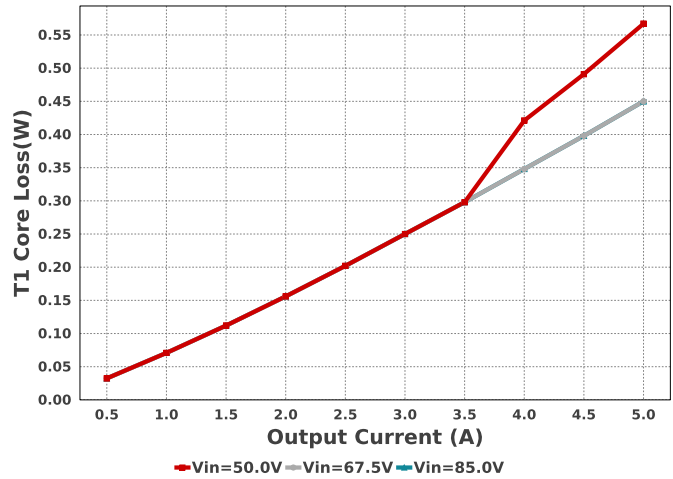




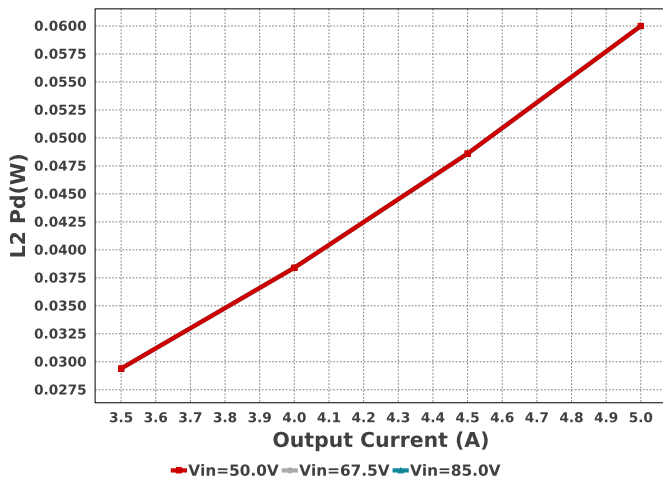
Rsns Pd



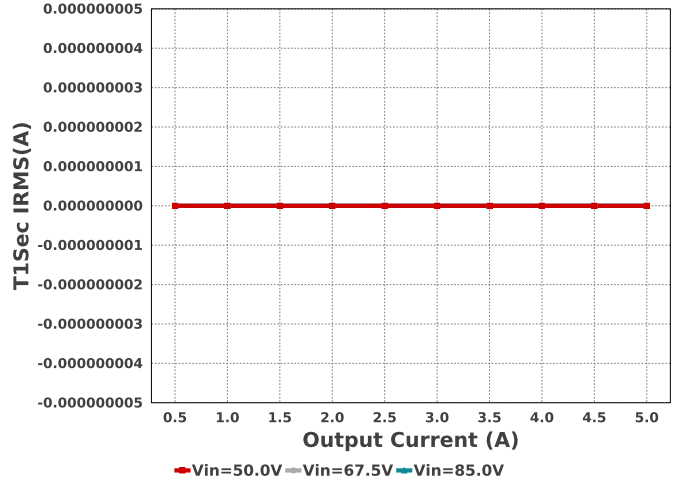
T1 Core Loss



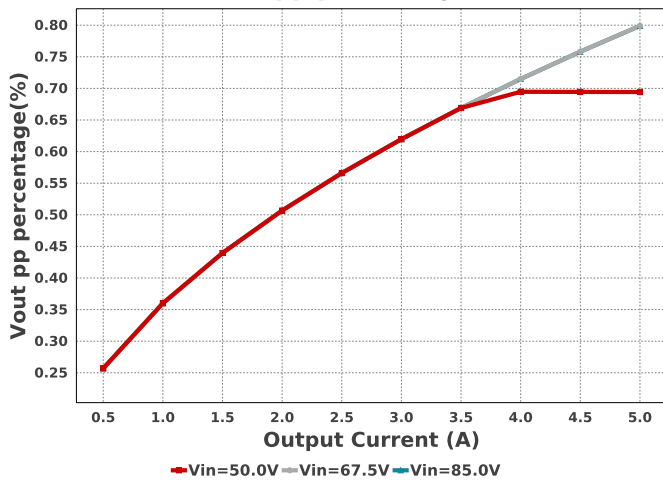
L2 Pd



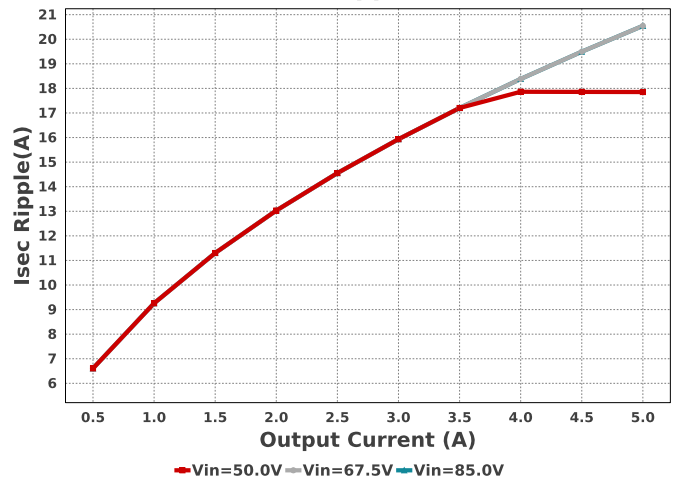
T1Sec IRMS

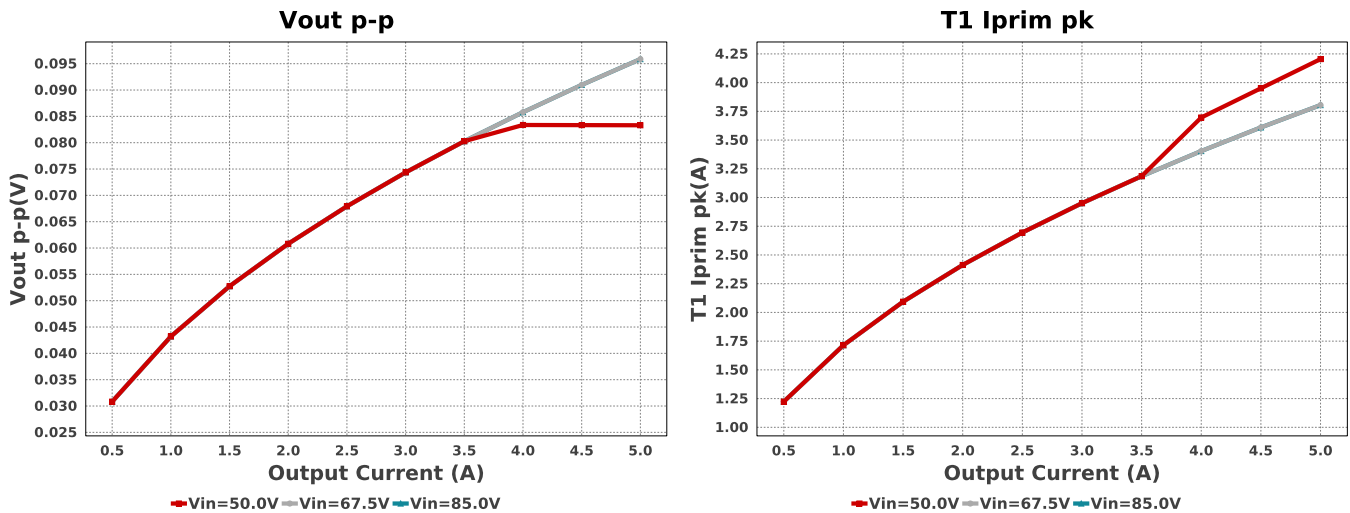


Vout pp percentage



Isec Ripple





## Operating Values

| #   | Name           | Value                   | Category    | Description   |
|-----|----------------|-------------------------|-------------|---|
| 1.  | Cin Pd         | 52.898 mW               | Capacitor   | Input capacitor power dissipation                                 |
| 2.  | Cout1 IRMS     | 8.014 A                 | Capacitor   | Output capacitor1 RMS ripple current                              |
| 3.  | Cout1 Pd       | 299.72 mW               | Capacitor   | Output capacitor1 power dissipation                               |
| 4.  | Daux trr       | 8.26 ns                 | Diode       | Auxiliary Diode Reverse Recovery Time                             |
| 5.  | Dsec Pd        | 804.95 mW               | Diode       | Secondary Diode Power Dissipation                                 |
| 6.  | Dsec Vf        | 321.979 mV              | Diode       | Effective Forward Voltage Drop at the Operating Current           |
| 7.  | Dsec trr       | 0.0 ns                  | Diode       | Output Diode Reverse Recovery Time                                |
| 8.  | Dsec2 Pd       | 804.95 mW               | Diode       | Secondary Diode Power Dissipation                                 |
| 9.  | Dsec2 Vf       | 321.979 mV              | Diode       | Effective Forward Voltage Drop at the Operating Current           |
| 10. | Dsnub trr      | 35.0 ns                 | Diode       | Snubber Diode Reverse Recovery Time                               |
| 11. | IC Pd          | 46.652 mW               | IC          | IC power dissipation  |
| 12. | IC Tj          | 51.013 degC             | IC          | IC junction temperature   |
| 13. | ICThetaJA      | 128.9 degC/W            | IC          | IC junction-to-ambient thermal resistance                         |
| 14. | Iin Avg        | 1.31 A                  | IC          | Average input current   |
| 15. | L2 Pd          | 60.0 mW                 | Inductor    | Average Power Dissipation in the Inductor Over the AC Line Period |
| 16. | M1 Pd          | 644.03 mW               | Mosfet      | M1 MOSFET total power dissipation                                 |
| 17. | M1 TjOP        | 114.02 degC             | Mosfet      | M1 MOSFET junction temperature                                    |
| 18. | Cin Pd         | 52.898 mW               | Power       | Input capacitor power dissipation                                 |
| 19. | Cout1 Pd       | 299.72 mW               | Power       | Output capacitor1 power dissipation                               |
| 20. | Dsec Pd        | 804.95 mW               | Power       | Secondary Diode Power Dissipation                                 |
| 21. | Dsec2 Pd       | 804.95 mW               | Power       | Secondary Diode Power Dissipation                                 |
| 22. | IC Pd          | 46.652 mW               | Power       | IC power dissipation  |
| 23. | L2 Pd          | 60.0 mW                 | Power       | Average Power Dissipation in the Inductor Over the AC Line Period |
| 24. | M1 Pd          | 644.03 mW               | Power       | M1 MOSFET total power dissipation                                 |
| 25. | Paux           | 18.523 mW               | Power       | Power Dissipation in Raux and Daux                                |
| 26. | Pd Rstartup    | 5.385 mW                | Power       | Power Dissipation in Rstartup1 and Rstartup2                      |
| 27. | Rdrv Pd        | 10.169 mW               | Power       | Power Dissipation in Gate Drive Resistor                          |
| 28. | Rfb Pd         | 12.37 mW                | Power       | Rfb Power Dissipation   |
| 29. | Rsns Pd        | 754.38 mW               | Power       | Current Limit Sense Resistor Power Dissipation                    |
| 30. | Snubber Pd     | 832.213 mW              | Power       | Snubber Power Dissipation   |
| 31. | T1 Copper Loss | 1.418 W                 | Power       | Transformer Copper Loss Power Dissipation                         |
| 32. | T1 Core Loss   | 540.0 mW                | Power       | Transformer Core Loss Power Dissipation                           |
| 33. | T1 Pd          | 1.958 W                 | Power       | Estimated Losses in Transformer                                   |
| 34. | Total Pd       | 5.499 W                 | Power       | Total Power Dissipation   |
| 35. | Pd Rstartup    | 5.385 mW                | Resistor    | Power Dissipation in Rstartup1 and Rstartup2                      |
| 36. | Rdrv Pd        | 10.169 mW               | Resistor    | Power Dissipation in Gate Drive Resistor                          |
| 37. | Rfb Pd         | 12.37 mW                | Resistor    | Rfb Power Dissipation   |
| 38. | Rsns Pd        | 754.38 mW               | Resistor    | Current Limit Sense Resistor Power Dissipation                    |
| 39. | BOM Count      | 40                      | System      | Total Design BOM count  |
| 40. | Duty Cycle     | 58.481 %                | Information | Duty cycle  |
| 41. | Efficiency     | 91.604 %                | Information | Steady state efficiency   |
| 42. | FootPrint      | 2.874 k mm <sup>2</sup> | Information | Total Foot Print Area of BOM components                           |
| 43. | Frequency      | 98.851 kHz              | Information | Switching frequency   |
| 44. | Iout           | 5.0 A                   | Information | Iout operating point  |
| 45. | Mode           | CCM                     | Information | Conduction Mode   |

| #   | Name                         | Value      | Category           | Description   |
|-----|------------------------------|------------|--------------------|---|
| 46. | Pout                         | 60.0 W     | System Information | Total output power  |
| 47. | Tdead                        | 0.0 ns     | System Information | Approximate Dead Time of the Regulator                                |
| 48. | Toff                         | 3.684 us   | System Information | Approximate Converter Off Time  |
| 49. | Ton Act                      | 5.916 us   | System Information | Approximate Converter On Time   |
| 50. | Total BOM                    | NA         | System Information | Total BOM Cost  |
| 51. | Tsw                          | 10.116 us  | System Information | Switching Time Period   |
| 52. | Vin                          | 50.0 V     | System Information | Vin operating point   |
| 53. | Vout                         | 12.0 V     | System Information | Operational Output Voltage  |
| 54. | Vout p-p                     | 83.093 mV  | System Information | Peak-to-peak output ripple voltage                                    |
| 55. | Vout pp percentage           | 692.445 m% | System Information | Output Voltage ripple percentage                                      |
| 56. | Vsnub                        | 116.64 V   | System Information | Voltage Across the Snubber  |
| 57. | Ipri Avg                     | 1.487 A    | Transformer        | Average Current in Primary Winding over the complete Switching Period |
| 58. | Ipri ripple                  | 3.297 A    | Transformer        | Ripple Current in the Primary Winding                                 |
| 59. | Ipri ripple pk-pk percentage | 129.695 %  | Transformer        | Primary Current pk-pk ripple percentage(of Ipri avg during ton only)  |
| 60. | Isec Ripple                  | 17.806 A   | Transformer        | Ripple Current in the Secondary Winding                               |
| 61. | Paux                         | 18.523 mW  | Transformer        | Power Dissipation in Raux and Daux                                    |
| 62. | T1 Copper Loss               | 1.418 W    | Transformer        | Transformer Copper Loss Power Dissipation                             |
| 63. | T1 Core Loss                 | 540.0 mW   | Transformer        | Transformer Core Loss Power Dissipation                               |
| 64. | T1 Iprim RMS                 | 2.076 A    | Transformer        | Transformer Primary RMS Current                                       |
| 65. | T1 Iprim pk                  | 4.191 A    | Transformer        | Transformer Primary Peak Current                                      |
| 66. | T1 Is1 RMS                   | 9.446 A    | Transformer        | Transformer Secondary1 RMS Current                                    |
| 67. | T1 Is1 pk                    | 22.632 A   | Transformer        | Transformer Secondary1 Peak Current                                   |
| 68. | T1 Pd                        | 1.958 W    | Transformer        | Estimated Losses in Transformer                                       |
| 69. | T1Pri IRMS                   | 2.018 A    | Transformer        | Transformer Primary RMS Current                                       |
| 70. | T1Sec IRMS                   | 9.251 A    | Transformer        | Transformer Secondary RMS Current                                     |
| 71. | Vaux                         | 14.88 V    | Transformer        | Auxiliary Voltage   |

## Design Inputs

| Name    | Value       | Description                 |
|---------|-------------|-----------------------------|
| Iout    | 5.0         | Maximum Output Current      |
| VinMax  | 85.0        | Maximum input voltage       |
| VinMin  | 50.0        | Minimum input voltage       |
| VinTyp  | 72.0        | Typical input voltage       |
| Vout    | 12.0        | Output Voltage              |
| base_pn | UCC28C53-Q1 | Base Product Number         |
| source  | DC          | Input Source Type           |
| Ta      | 45.0        | Ambient temperature         |
| UserFsw | 199.0 k     | Customer Selected Frequency |

## WEBENCH® Assembly

### Component Testing

Some published data on components in datasheets such as Capacitor ESR and Inductor DC resistance is based on conservative values that will guarantee that the components always exceed the specification. For design purposes it is usually better to work with typical values. Since this data is not always available it is a good practice to measure the Capacitance and ESR values of  $C_{in}$  and  $C_{out}$ , and the inductance and DC resistance of  $L1$  before assembly of the board. Any large discrepancies in values should be electrically simulated in WEBENCH to check for instabilities and thermally simulated in WebTHERM to make sure critical temperatures are not exceeded.

### Soldering Component to Board

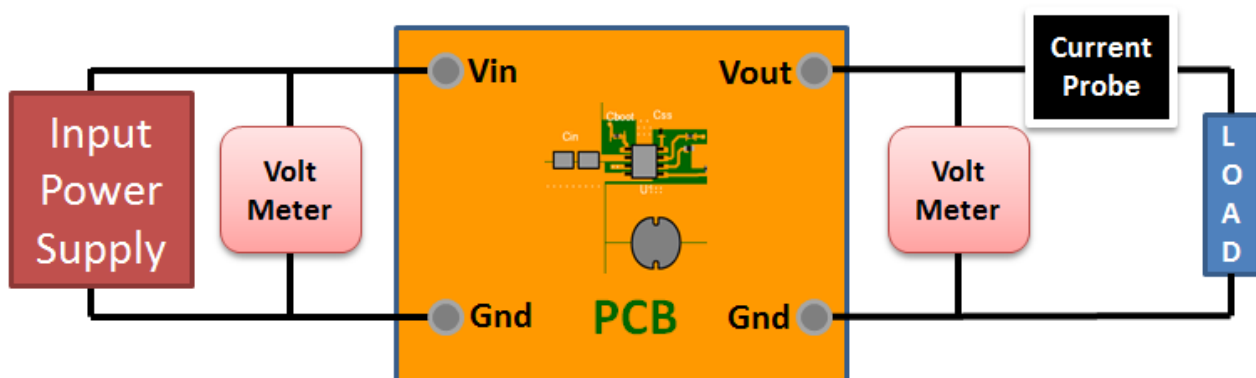
If board assembly is done in house it is best to tack down one terminal of a component on the board then solder the other terminal. For surface mount parts with large tabs, such as the DPAK, the tab on the back of the package should be pre-tinned with solder, then tacked into place by one of the pins. To solder the tab town to the board place the iron down on the board while resting against the tab, heating both surfaces simultaneously. Apply light pressure to the top of the plastic case until the solder flows around the part and the part is flush with the PCB. If the solder is not flowing around the board you may need a higher wattage iron (generally 25W to 30W is enough).

### Initial Startup of Circuit

It is best to initially power up the board by setting the input supply voltage to the lowest operating input voltage 50.0V and set the input supply's current limit to zero. With the input supply off connect up the input supply to  $V_{in}$  and GND. Connect a digital volt meter and a load if needed to set the minimum lout of the design from  $V_{out}$  and GND. Turn on the input supply and slowly turn up the current limit on the input supply. If the voltage starts to rise on the input supply continue increasing the input supply current limit while watching the output voltage. If the current increases on the input supply, but the voltage remains near zero, then there may be a short or a component misplaced on the board. Power down the board and visually inspect for solder bridges and recheck the diode and capacitor polarities. Once the power supply circuit is operational then more extensive testing may include full load testing, transient load and line tests to compare with simulation results.

### Load Testing

The setup is the same as the initial startup, except that an additional digital voltmeter is connected between  $V_{in}$  and GND, a load is connected between  $V_{out}$  and GND and a current meter is connected in series between  $V_{out}$  and the load. The load must be able to handle at least rated output power + 50% ( 7.5 watts for this design). Ideally the load is supplied in the form of a variable load test unit. It can also be done in the form of suitably large power resistors. When using an oscilloscope to measure waveforms on the prototype board, the ground leads of the oscilloscope probes should be as short as possible and the area of the loop formed by the ground lead should be kept to a minimum. This will help reduce ground lead inductance and eliminate EMI noise that is not actually present in the circuit.



## WEBENCH® Transformer Report

| #  | Name                     | Value           |
|----|--------------------------|-----------------|
| 1. | Core Part Number         | B66421G0000X197 |
| 2. | Core Manufacturer        | TDK             |
| 3. | Coil Former Part Number  | B66422W1010D001 |
| 4. | Coil Former Manufacturer | TDK             |

### Transformer Electrical Diagram

#### Primary

|                 |                                   |
|-----------------|-----------------------------------|
| Turns           | 27.0                              |
| AWG             | 28.0                              |
| Layers          | 2.0                               |
| Strands         | 3.0                               |
| Insulation Type | Heavy<br>Insulated<br>Magnet Wire |

#### Secondary

|                 |                     |
|-----------------|---------------------|
| Turns           | 5.0                 |
| AWG             | 26.0                |
| Layers          | 1.0                 |
| Strands         | 4.0                 |
| Insulation Type | Triple<br>Insulated |

#### Auxiliary

|                 |                                   |
|-----------------|-----------------------------------|
| Turns           | 6.0                               |
| AWG             | 28.0                              |
| Layers          | 1.0                               |
| Strands         | 4.0                               |
| Insulation Type | Heavy<br>Insulated<br>Magnet Wire |

### Transformer Construction Diagram

### Winding Instruction

| Winding                    | AWG  | Turns | Winding Orientation |
|----------------------------|------|-------|---------------------|
| Primary First 1/2.0        | 28.0 | 14    | Clockwise           |
| Triple Insulated Secondary | 26.0 | 5.0   | Counter Clockwise   |
| Auxiliary                  | 28.0 | 6.0   | Counter Clockwise   |
| Primary Second 1/2.0       | 28.0 | 13    | Clockwise           |

### Transformer Parameters

| #  | Name                  | Value      |
|----|-----------------------|------------|
| 1. | Lpri                  | 8.7E-5H    |
| 2. | Inductance Factor(AI) | 120.0nH    |
| 3. | Npri                  | 27.0       |
| 4. | Nsec                  | 5.0        |
| 5. | Naux                  | 6.0        |
| 6. | Core Type             | EFD25/13/9 |
| 7. | Core Material         | N97        |

| #   | Name                | Value    |
|-----|---------------------|----------|
| 8.  | Bmax                | 0.23T    |
| 9.  | Switching Frequency | 98.85kHz |
| 10. | DMax                | 0.6      |
| 11. | Ipk(Primary)        | 4.11A    |
| 12. | Irms(Primary)       | 2.02A    |
| 13. | Ipk(Secondary)      | 22.2A    |
| 14. | Irms(Secondary)     | 8.9A     |

## Design Assistance

1. Feature Highlights: This device provides the features that are necessary to implement off-line or dc-to-dc fixed-frequency current-mode control schemes, with a minimum number of external components.

2. The UCC28C53-Q1 is qualified for Automotive applications. All passives and other components selected in this design may not be qualified for Automotive applications. The user is required to verify that all components in the design meet the qualification and safety requirements for their specific application

3. Master key : FCC71AEA8B535B1B[v1]

4. **UCC28C53-Q1** Product Folder : <https://www.ti.com/product/UCC28C53%2DQ1> : contains the data sheet and other resources.

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